

FAIRCHILD
A Schlumberger Company

FRM3200CC Series T-03-19
Ultra-fast POWERplanar™
Rectifiers 32 A, 50-200 V

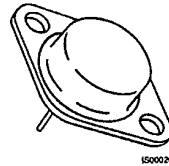
Power And Discrete Division

Description

Designed for use in switching power supplies, inverters and as free-wheeling diodes, these state-of-the-art devices have the following features:

- Ultrafast 35 ns Reverse Recovery Time
- Soft Recovery ($S > 0.5$)
- Low $I_{R(REC)}$
- 150°C Operating Junction Temperature
- Popular TO-204AA Package (Formerly TO-3)
- Low V_{FM}

TO-204AA



FRM3205CC
FRM3210CC
FRM3215CC
FRM3220CC

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Maximum Ratings

Symbol	Rating	FRM3205CC	FRM3210CC	FRM3215CC	FRM3220CC	Unit
V_{RRM}	Peak Repetitive Reverse Voltage	50	100	150	180	V
V_{RSM}	Non-repetitive Peak Reverse Voltage	50	100	150	200	
V_R	DC Blocking Voltage	50	100	150	180	
$I_{F(AV)}$	Average Rectified Forward Current, $T_C = 107^\circ\text{C}$, Rated V_R	32	32	32	32	A
I_{FRM}	Peak Repetitive Forward Current Rated V_R , Square Wave, 50 kHz, $T_C = 107^\circ\text{C}$	64	64	64	64	A
I_{FSM}	Non-repetitive Peak Surge Current per Diode, Surge Applied at Rate Load Conditions Halfwave, Single Phase, 60 Hz	200	200	200	200	A
T_J, T_{stg}	Operating Junction Temperature and Storage Temperature	-55 to +150	-55 to +150	-55 to +150	-55 to +150	°C

Maximum Thermal Characteristics

Symbol	Rating	FRM3205CC	FRM3210CC	FRM3215CC	FRM3220CC	Unit
$R_{\theta JC}$	Maximum Thermal Resistance, Junction to Case	1.0	1.0	1.0	1.0	°C/W
$R_{\theta JA}$	Maximum Thermal Resistance, Junction to Ambient	60	60	60	60	

Notes

For information concerning connection diagram and package outline, refer to Section 7.

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Symbol	Rating	FRM3205CC	FRM3210CC	FRM3215CC	FRM3220CC	Unit
Electrical Characteristics per Diode						
V_{FM}^1	Maximum Instantaneous Forward Voltage per Diode $I_F = 16 \text{ A}, T_C = 150^\circ\text{C}$ $I_F = 16 \text{ A}, T_C = 25^\circ\text{C}$	0.80 0.95	0.80 0.95	0.80 0.95	0.80 0.95	V
I_{RRM}^1	Maximum Instantaneous Reverse Current per Diode Rated DC Voltage, $T_C = 125^\circ\text{C}$ Rated DC Voltage, $T_C = 25^\circ\text{C}$	10 25	10 25	10 25	10 25	mA μA
t_{rr}	Maximum Reverse Recovery Time $I_F = 1.0 \text{ A}, di_F/dt = 50 \text{ A}/\mu\text{s}$ $I_F = 16 \text{ A}, di_F/dt = 100 \text{ A}/\mu\text{s}$	35 50	35 50	35 50	35 50	ns
$I_{R(REC)}^2$	Maximum Reverse Recovery Current $I_F = 16 \text{ A}, di_F/dt = 100 \text{ A}/\mu\text{s},$ $V_R = V_{RRM}$	2.5	2.5	2.5	2.5	A

Notes

1. Pulse Test: Pulse Width = 300 μs . Duty Cycle $\leq 2.0\%$
2. See Figure 10 for test conditions.

Performance Curves per Diode

Figure 1 Maximum Forward Voltage Drop

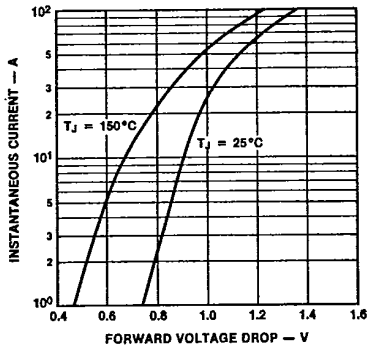
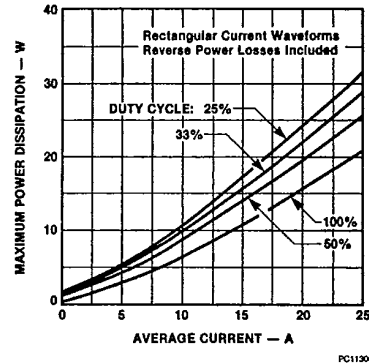


Figure 2 Maximum Power Dissipation



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Performance Curves per Diode (Cont.)

Figure 3 Transient Thermal Resistance

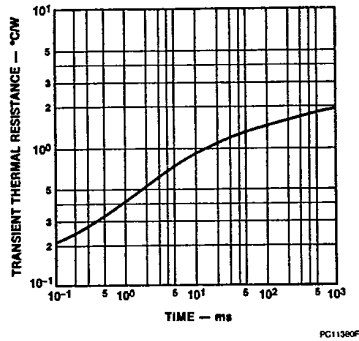


Figure 4 Typical Reverse Leakage Current

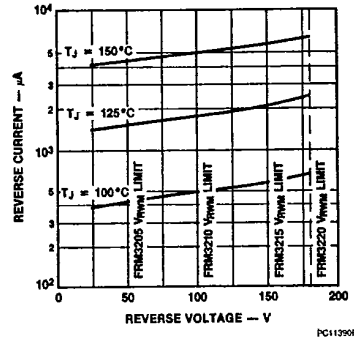


Figure 5 Average Power Derating

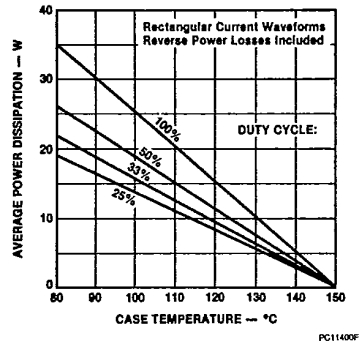


Figure 6 Reverse Recovery Charge

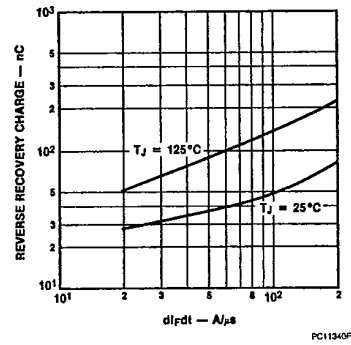
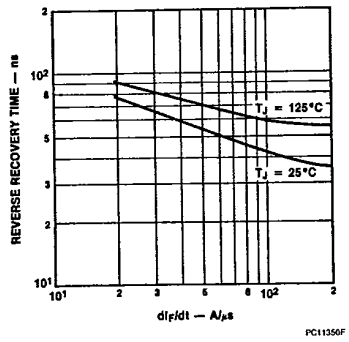


Figure 7 Reverse Recovery Time



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Performance Curves per Diode (Cont.)

Figure 8 Reverse Recovery Current

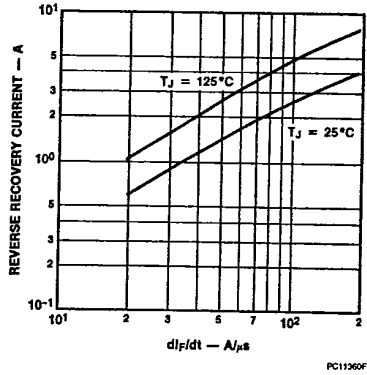


Figure 9 Reverse Recovery Softness

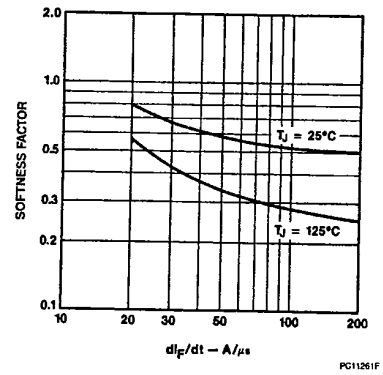


Figure 10 Reverse Recovery Test Waveform

